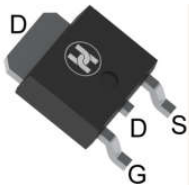
N-CHANNEL Power MOSFET

FEATURES

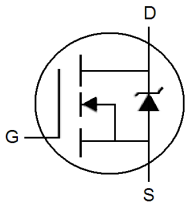
- V_{DS}: 500V Min, I_D: 5A Max.
- $R_{DS(ON)}$:1.7Ω(max.)@V_{GS}=10V,I_D=1A
- $R_{DS(ON)}$:1.6Ω(max.)@V_{GS}=10V ,I_D=2.5A
- High density cell design for ultra low on-resistance
- Fully characterized avalanche voltage and current



TO-252

MECHANICAL DATA

- Case: TO-252
- Case material: Molded Plastic. UL flammability 94V-0
- Weight:0.33grams(approximate)
- Marking:D5N50



EQUIVALENT CIRCUIT

MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V_{DS}	500	V
Gate-source voltage	V_{GS}	±30	V
Continuous drain current, V_{GS}=10V	I_D	5	A
Pulsed drain current (Note 1)	I_{DM}	16	A
Power dissipation	P_D	22	W
Thermal resistance from junction to ambient	$R_{\theta JA}$	110	C/W
Operating junction and storage temperature	T_J,T_{STG}	-55~+150	°C
Single Pulsed Avalanche Energy (note 1)	E_{AS}	12	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10s)	T_L	260	°C

Note: 1. E_{AS} condition: V_{DD}=20V,L=0.5mH, R_G=25Ω, Starting T_J = 25°C

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ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Off characteristics						
Drain-Source breakdown voltage	$V_{(BR)DS}$	500			V	V_{GS}=0V,I_D=250μA
Zero gate voltage drain current	I_{DSS}			100	nA	V_{DS}=500V, V_{GS}=0V
Gate-body leakage current	I_{GSS}			±90	nA	V_{DS}=0V, V_{GS}=±30V
On characteristics (note1)						
Gate-threshold voltage	$V_{GS(th)}$	2.0	-	4.0	V	V_{DS}=V_{GS}, I_D=250μA
Drain-source on-resistance	$R_{DS(ON)}$		1.45	1.7	Ω	V_{GS}=10V, I_D=1A
			1.35	1.6		V_{GS}=10V,I_D= 2.5A
Forward transconductance	g_{FS}		5		S	V_{DS}=40V,I_D=2A
Dynamic characteristics (Guaranteed by design, not subject to production)						
Input capacitance	C_{iss}		480		pF	V_{GS}=0V V_{DS}=25V f=1.0MHz
Output capacitance	C_{oss}		80		pF	
Reverse transfer capacitance	C_{rss}		15		pF	
Switching characteristics (Guaranteed by design, not subject to production)						
Turn-on delay time	$t_{d(on)}$		12		ns	V_{DD}=250V I_D=5 A R_G=25Ω V_{GS}=10V
Turn-on rise time	t_r		46		ns	
Turn-off delay time	$t_{d(off)}$		50		ns	
Turn-off fall time	t_f		48		ns	
Total gate charge	Q_g		12.8		nC	V_{DS}=400V, V_{GS}=5V I_D=5A
Gate-source charge	Q_{gs}		4		nC	
Gate-drain charge	Q_{gd}		4.5		nC	
Drain-source diode characteristics						
Diode forward voltage	V_{SD}			1.5	V	I_S=5A, V_{GS}=0V
Max. forward current	I_S			5	A	
Pulsed drain-source diode forward current	I_{SM}			16	A	

Notes: 1. Pulse Test: Pulse Width≤300μs, duty cycle ≤2%.

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TYPICAL CHARACTERISTICS

Figure 1. Typical Output Characteristics

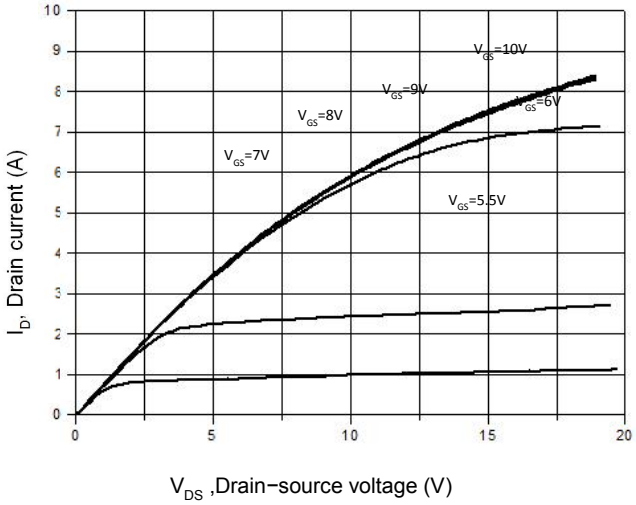


Figure 2. Transfer Characteristics

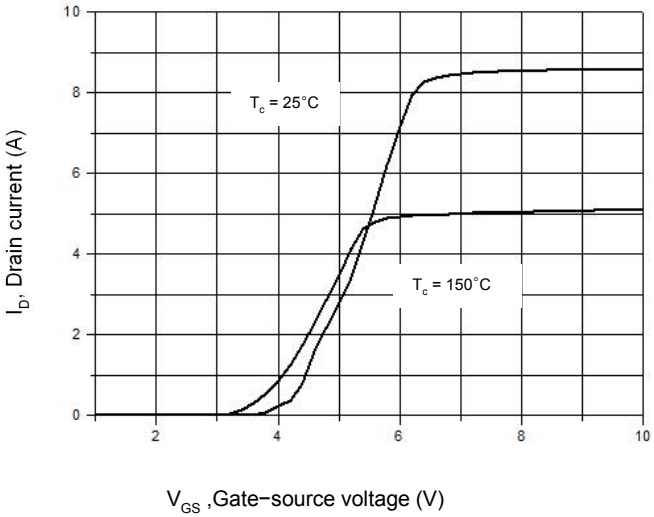


Figure 3. On-Resistance Variation vs. Drain Current

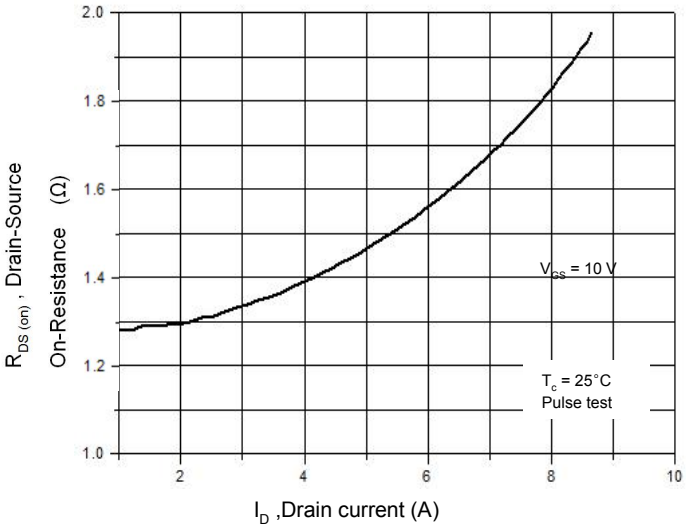


Figure 4. Threshold Voltage vs. Temperature

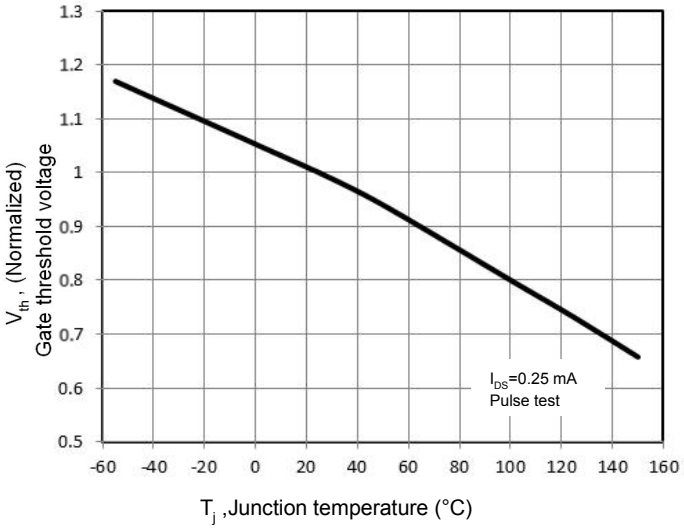


Figure 5. Breakdown Voltage vs. Temperature

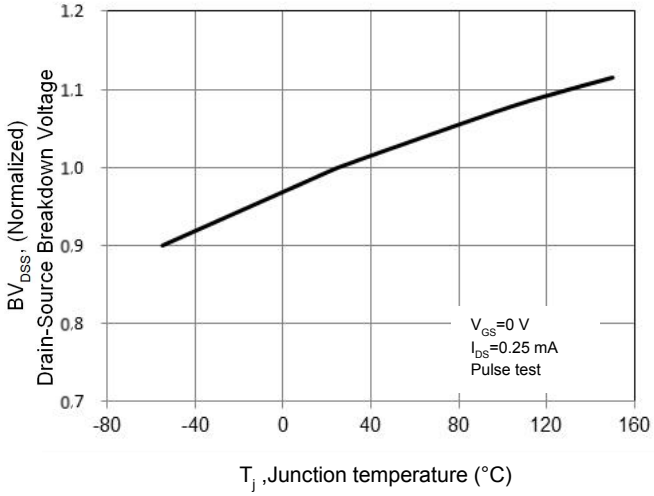
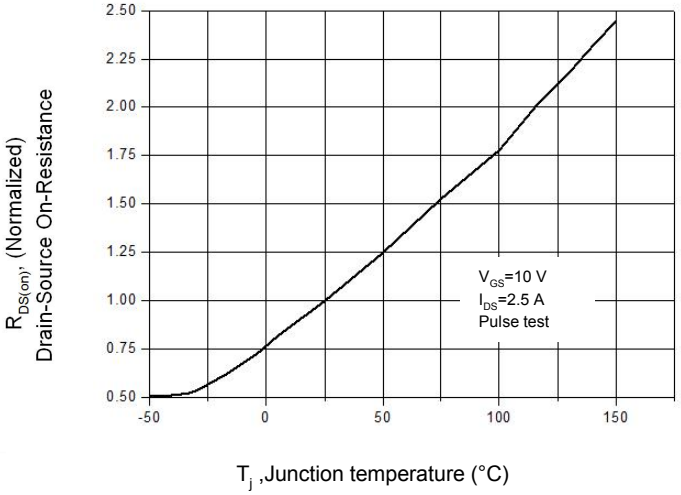


Figure 6. On-Resistance vs. Temperature



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TYPICAL CHARACTERISTICS

Figure 7 . Continuous Drain Current vs. Temperature

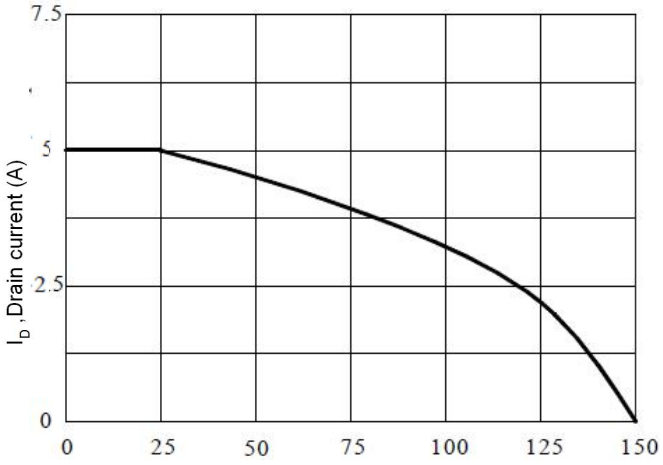


Figure 8 . Body Diode Transfer Characteristics

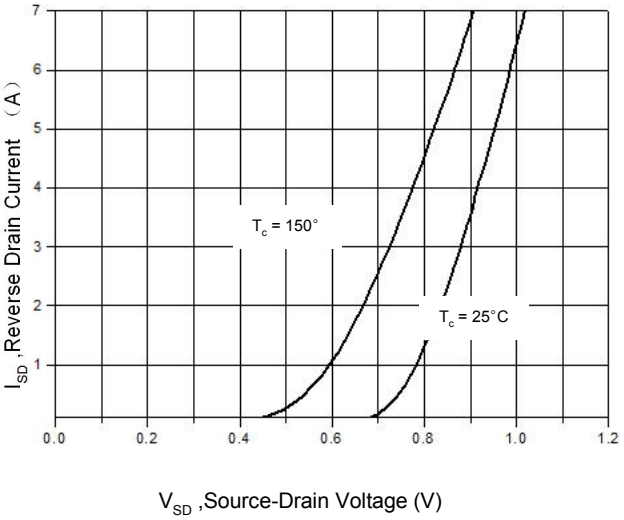
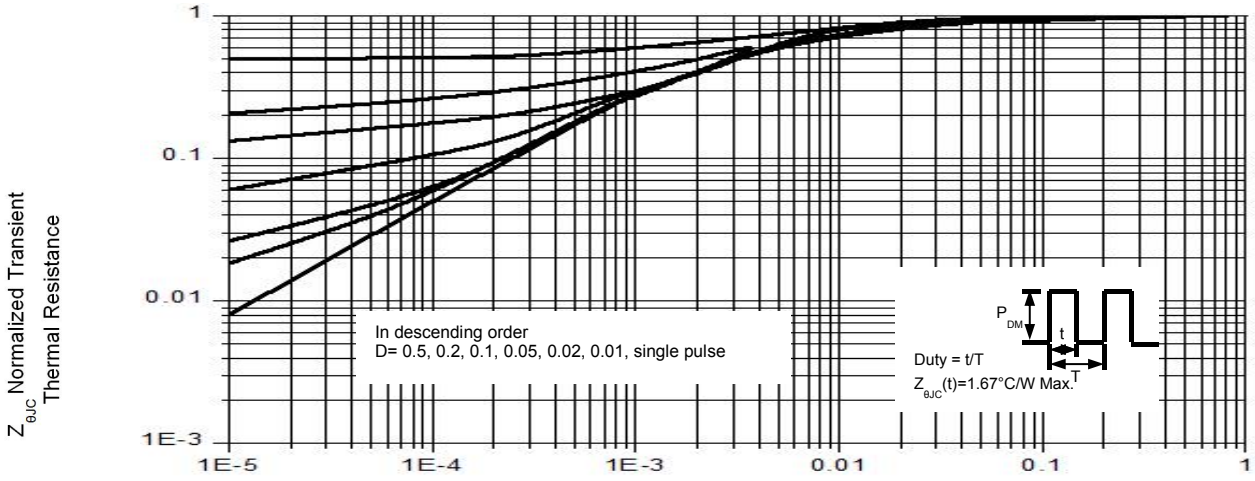


Figure 9 . Transient Thermal Impedance, Junction to Case



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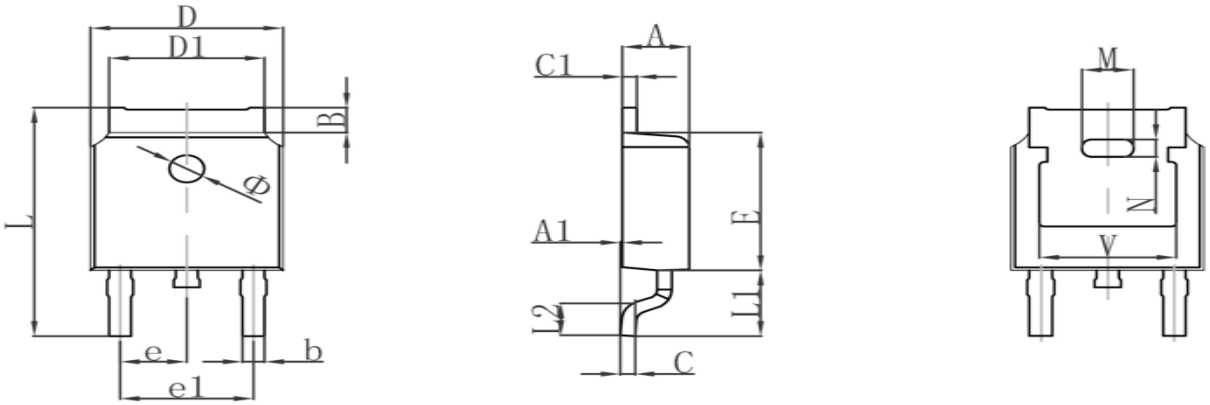
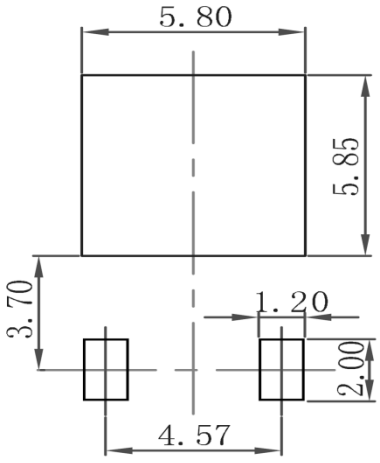
TO-252 PACKAGE OUTLINE DIMENSIONS



Symbol	DimensionsIn Millimeters		DimensionsIn Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.380	0.087	0.094
A1	0.000	0.100	0.000	0.004
B	0.800	1.400	0.031	0.055
b	0.710	0.810	0.028	0.032
c	0.460	0.560	0.018	0.022
c1	0.460	0.560	0.018	0.022
D	6.500	6.700	0.256	0.264
D1	5.130	5.460	0.202	0.215
E	6.000	6.200	0.236	0.244
e	2.286TYP		0.090TYP	
e1	4.327	4.727	0.170	0.186
M	1.778REF		0.070REF	
N	0.762REF		0.018REF	
L	9.800	10.400	0.386	0.409
L1	2.9REF		0.114REF	
L2	1.400	1.700	0.055	0.067
V	4.830REF		0.190REF	
Φ	1.100	1.300	0.043	0.051

TO-252 SUGGESTED PAD LAYOUT



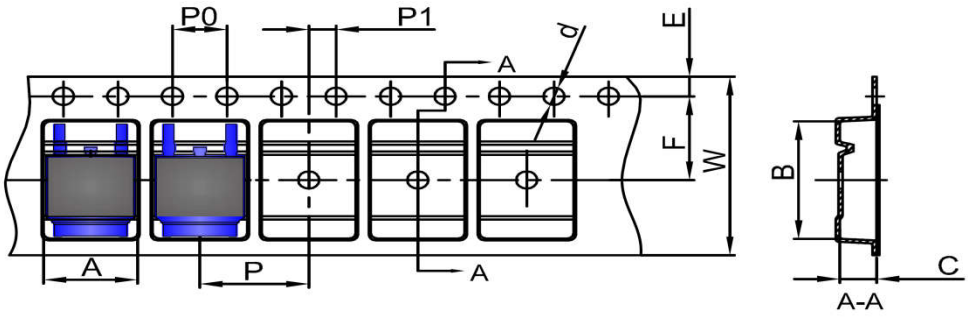
Note:

1. Controlling dimension: in millimeters
2. General tolerance: ±0.05mm
3. The pad layout is for reference purposes only

N-CHANNEL Power MOSFET

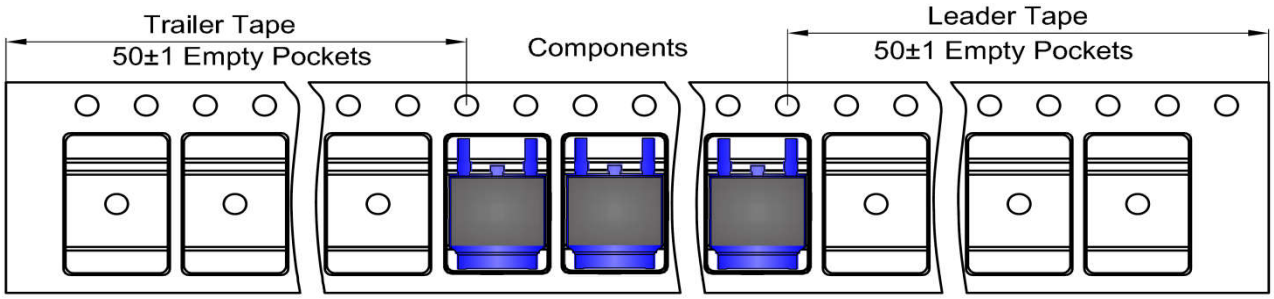
TO-252 TAPE AND REEL

TO-252 Embossed Carrier Tape

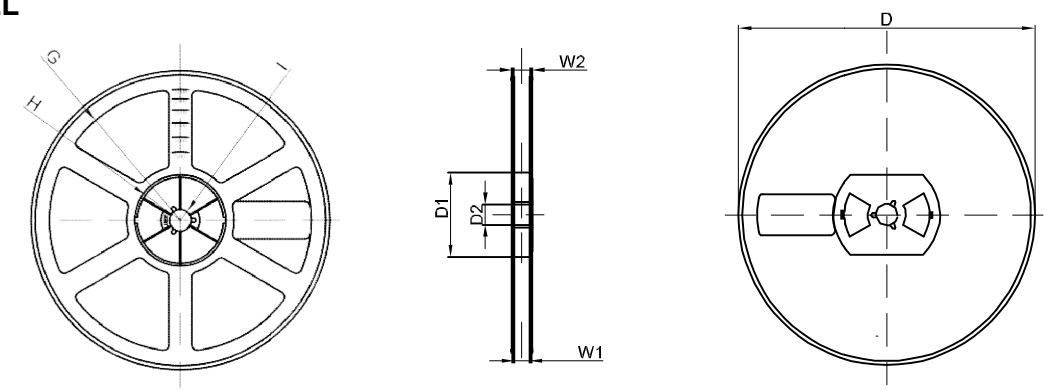


	DIMENSIONS ARE IN MILLIMETER									
TYPE	A	B	C	d	E	F	P0	P	P1	W
TO-252	6.90	10.50	2.70	Ø1.55	1.75	7.50	4.00	8.00	2.00	16.00
TOLERANCE	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1

TO-252 Tape Leader and Trailer



TO-252 REEL



	DIMENSIONS ARE IN MILLIMETER							
REEL OPTION	D	D1	D2	G	H	I	W1	W2
13” DIA	Ø330.00	100.00	Φ21.00	R151.00	R56.00	R6.50	16.40	21.00
TOLERANCE	±2	±1	±1	±1	±1	±1	±1	±1